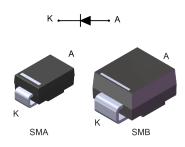


200 V - 2 A ultrafast recovery diode



Features

- Very low conduction losses
- Negligible switching losses
- · Low forward voltage drop
- · High junction temperature
- ECOPACK[®]2 compliant

Applications

- · Switching diode
- LED Lighting
- · Auxiliary power supply
- · Flyback diode

Description

The STTH2R02 uses ST's patented 200 V planar Pt doping technology, and it is specially suited for switching mode base drive and transistor circuits.

Packaged in SMA, SMB, the STTH2R02 is optimized for use low voltage, high frequency inverters, free wheeling and polarity protection

Product status
STTH2R02

Product summary				
Symbol Value				
I _{F(AV)}	2 A			
V _{RRM}	200 V			
T _{j(max.)} 175 °C				
$V_{F(typ.)}$	0.7 V			
trr(typ.)	15 ns			



1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			200	V
1	Average forward average \$ = 0.5 assume views	SMA	T _L = 90 °C	2	_
I _{F(AV)}	Average forward current δ = 0.5, square wave		T _L = 90 °C	2	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$				Α
T _{stg}	Storage temperature range				°C
Tj	Operating junction temperature			+175	°C

Table 2. Thermal resistance parameter

Symbol	Parame	Parameter		
R _{th(j-l)}	Junction to lead	SMA / SMB	30	°C/W

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ R	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		3	
		T _j = 125 °C	VR - VRRM	-	2	20	μA
V _F ⁽²⁾ Forward voltage drop		T _j = 25 °C	I _F = 6 A	-		1.20	
	Forward voltage drop	T _j = 25 °C		-	0.89	1.00	V
		T _j = 100 °C	I _F = 2 A	-	0.76	0.85	V
		T _j = 150 °C		-	0.70	0.80	

- 1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$
- 2. Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses, use the following equation:

 $P = 0.68 \times I_{F(AV)} + 0.06 \times I_{F}^{2}_{(RMS)}$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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Table 4. Dynamic characteristics (T_j = 25 °C unless otherwise specified)

Symbol	Parameters	Test conditions	Min.	Тур.	Max.	Unit
t Poverse recovery time		I_F = 1 A, dI_F/dt = -50 A/ μ s, V_R = 30 V	-	23	30	ns
t _{rr} Reverse recovery time	$I_F = 1 \text{ A}, dI_F/dt = -100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$	-	15	20	115	
I _{RM}	Reverse recovery current	I_F = 2 A, dI_F/dt = -200 A/µs, V_R = 160 V, T_j = 125 $^{\circ}C$	-	3	4	Α
t _{fr}	Forward recovery time	$I_F = 2 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_{FR} = 1.1 \text{ V}_{F(max.)}$	-	40		ns
V _{FP}	Forward recovery voltage	$I_F = 2 \text{ A}$, $dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	2.0		V

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1.1 Characteristics (curves)

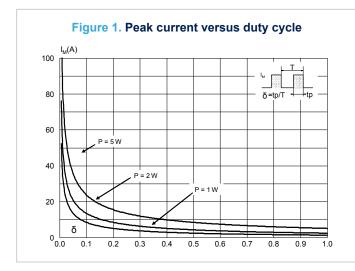
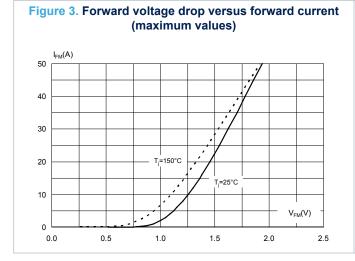
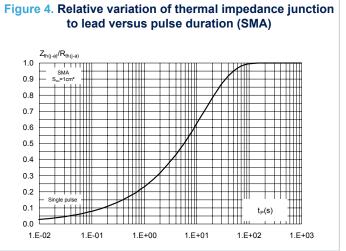


Figure 2. Forward voltage drop versus forward current (typical values) $I_F(A)$ 50 40 30 20 T_j=25°C 10 $V_F(V)$ 0 0.5 0.0 1.0 1.5 2.0 2.5





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Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration (SMB)

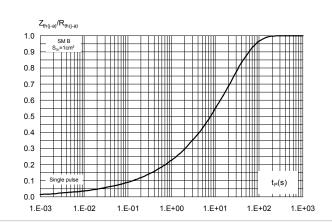


Figure 6. Junction capacitance versus reverse voltage applied (typical values)

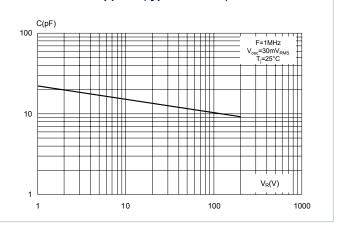


Figure 7. Reverse recovery charges versus dI_F/dt (typical values)

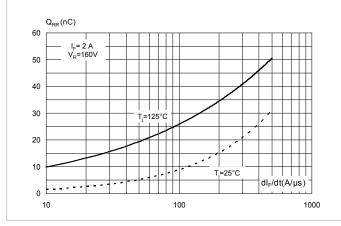


Figure 8. Reverse recovery time versus dI_F/dt (typical values)

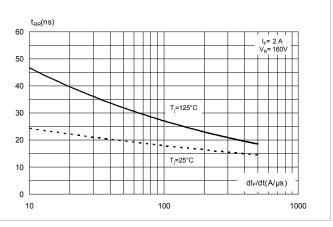


Figure 9. Peak reverse recovery current versus dl_F/dt (typical values)

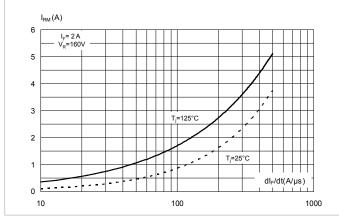
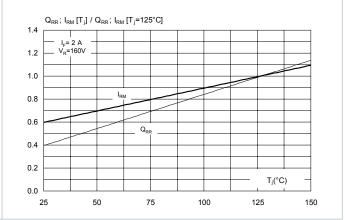


Figure 10. Relative variations of dynamic parameters versus junction temperature



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Figure 11. Thermal resistance junction to ambient versus copper surface under each lead (typical values)

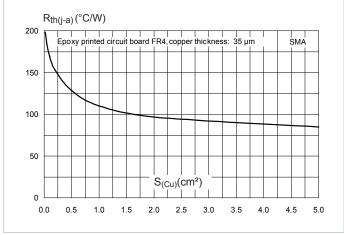
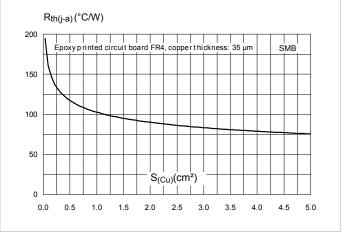


Figure 12. Thermal resistance junction to ambient versus copper surface under each lead (typical values)



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 SMA package information

- Epoxy meets UL94, V0
- Cooling method : by conduction (C)

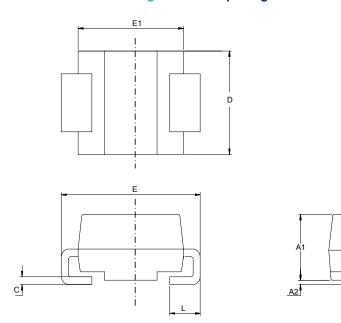


Figure 13. SMA package outline

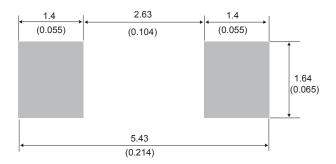


	Dimensions				
Ref.	Millin	neters	Inches (for reference only)		
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.074	0.097	
A2	0.05	0.20	0.001	0.008	
b	1.25	1.65	0.049	0.065	
С	0.15	0.40	0.005	0.016	
D	2.25	2.90	0.088	0.115	
E	4.80	5.35	0.188	0.211	
E1	3.95	4.60	0.155	0.182	
L	0.75	1.50	0.029	0.060	

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Figure 14. SMA recommended footprint in mm (inches)



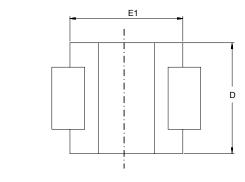
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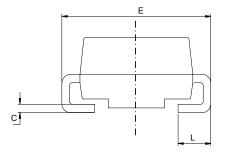


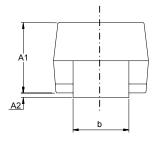
2.2 SMB package information

- Epoxy meets UL94, V0
- Lead-free package

Figure 15. SMB package outline







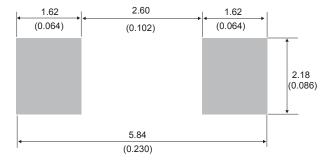
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Table 6. SMB package mechanical data

	Dimensions					
Ref.	Millin	neters	Inches (for reference only)			
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.074	0.097		
A2	0.05	0.20	0.001	0.008		
b	1.95	2.20	0.076	0.087		
С	0.15	0.40	0.005	0.016		
D	3.30	3.95	0.129	0.156		
E	5.10	5.60	0.200	0.221		
E1	4.05	4.60	0.159	0.182		
L	0.75	1.50	0.029	0.060		

Figure 16. SMB recommended footprint



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3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH2R02A	R2A	SMA	0.068 g	5000	Tape and reel
STTH2R02U	R2U	SMB	0.107 g	2500	Tape and reel

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Revision history

Table 8. Document revision history

Date	Revision	Changes
03-May-2006	1	First issue.
13-Oct-2006	2	Maximum T _j set to 175° C for all packages in Table 1.
11-Dec-2018	3	Removed DO-15 package information.

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ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077
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